

November 1983 Revised April 2002

# CD4051BC • CD4052BC • CD4053BC Single 8-Channel Analog Multiplexer/Demultiplexer • Dual 4-Channel Analog Multiplexer/Demultiplexer • Triple 2-Channel Analog Multiplexer/Demultiplexer

### **General Description**

The CD4051BC, CD4052BC, and CD4053BC analog multiplexers/demultiplexers are digitally controlled analog switches having low "ON" impedance and very low "OFF" leakage currents. Control of analog signals up to  $15 V_{p-p}$  can be achieved by digital signal amplitudes of 3-15 V. For example, if  $V_{DD}=5 V$ ,  $V_{SS}=0 V$  and  $V_{EE}=-5 V$ , analog signals from -5 V to +5 V can be controlled by digital inputs of 0-5 V. The multiplexer circuits dissipate extremely low quiescent power over the full  $V_{DD}-V_{SS}$  and  $V_{DD}-V_{EE}$  supply voltage ranges, independent of the logic state of the control signals. When a logical "1" is present at the inhibit input terminal all channels are "OFF".

CD4051BC is a single 8-channel multiplexer having three binary control inputs. A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned "ON" and connect the input to the output.

CD4052BC is a differential 4-channel multiplexer having two binary control inputs, A and B, and an inhibit input. The two binary input signals select 1 or 4 pairs of channels to be turned on and connect the differential analog inputs to the differential outputs.

CD4053BC is a triple 2-channel multiplexer having three separate digital control inputs, A, B, and C, and an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole double-throw configuration.

### **Features**

- Wide range of digital and analog signal levels: digital 3 15V, analog to 15V<sub>p-p</sub>
- Low "ON" resistance:  $80\Omega$  (typ.) over entire  $15V_{p-p}$  signal-input range for  $V_{DD} V_{EE} = 15V$
- High "OFF" resistance: channel leakage of ±10 pA (typ.) at V<sub>DD</sub> - V<sub>EE</sub> = 10V
- Logic level conversion for digital addressing signals of 3 - 15V (V<sub>DD</sub> - V<sub>SS</sub> = 3 - 15V) to switch analog signals to 15 V<sub>D-D</sub> (V<sub>DD</sub> - V<sub>EE</sub> = 15V)
- Matched switch characteristics:  $\Delta R_{ON} = 5\Omega$  (typ.) for  $V_{DD} V_{EE} = 15V$
- Very low quiescent power dissipation under all digital-control input and supply conditions: 1 µ W (typ.) at V<sub>DD</sub> - V<sub>SS</sub> = V<sub>DD</sub> - V<sub>EE</sub> = 10V
- Binary address decoding on chip

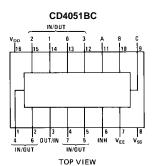
### **Ordering Code:**

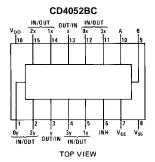
Order Number	Package Number	Package Description
CD4051BCM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4051BCSJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4051BCMTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
CD4051BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
CD4052BCM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4052BCSJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4052BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
CD4053BCM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4053BCSJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4053BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code

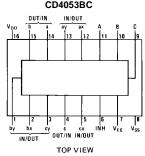
### **Connection Diagrams**

Pin Assignments for DIP and SOIC





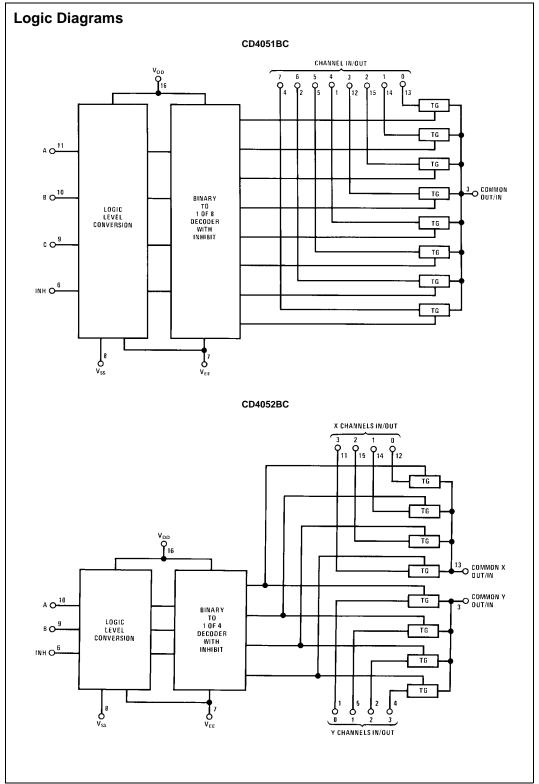
### CD4053BC

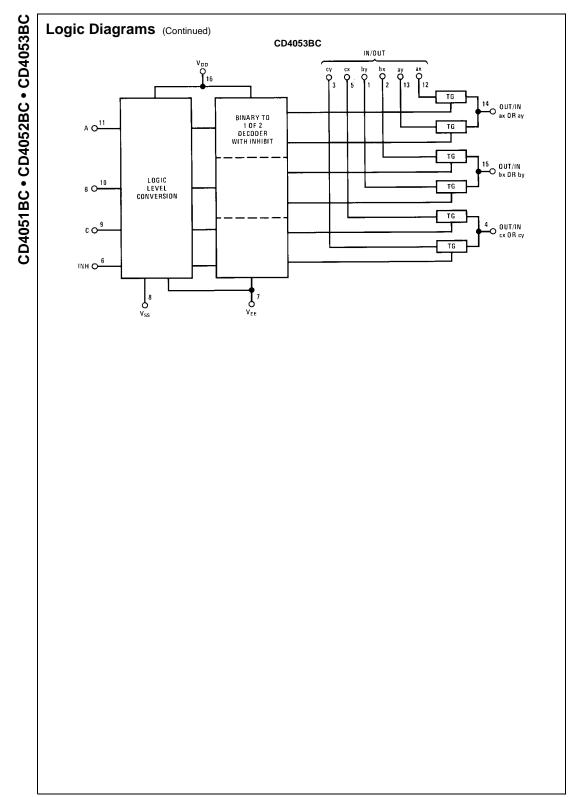


### **Truth Table**

INPUT STATES				"ON" CHANNELS				
INHIBIT	С	В	Α	CD4051B CD4052B		CD4053B		
0	0	0	0	0	0X, 0Y	cx, bx, ax		
0	0	0	1	1	1X, 1Y	cx, bx, ay		
0	0	1	0	2	2X, 2Y	cx, by, ax		
0	0	1	1	3	3X, 3Y	cx, by, ay		
0	1	0	0	4		cy, bx, ax		
0	1	0	1	5		cy, bx, ay		
0	1	1	0	6		cy, by, ax		
0	1	1	1	7		cy, by, ay		
1	*	*	*	NONE	NONE	NONE		

\*Don't Care condition.





### **Absolute Maximum Ratings**(Note 1)

DC Supply Voltage (V<sub>DD</sub>)  $-0.5 \text{ V}_{DC} \text{ to +18 V}_{DC}$  Input Voltage (V<sub>IN</sub>)  $-0.5 \text{ V}_{DC} \text{ to V}_{DD} +0.5 \text{ V}_{DC}$ 

Storage Temperature

Range ( $T_S$ )  $-65^{\circ}C$  to  $+150^{\circ}C$ 

Power Dissipation (P<sub>D</sub>)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature  $(T_L)$ 

(soldering, 10 seconds) 260°C

# Recommended Operating Conditions

DC Supply Voltage (V<sub>DD</sub>) +5 V<sub>DC</sub> to +15 V<sub>DC</sub> Input Voltage (V<sub>IN</sub>) 0V to V<sub>DD</sub> V<sub>DC</sub>

Operating Temperature Range (T<sub>A</sub>)

CD4051BC/CD4052BC/CD4053BC -55°C to +125°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions

for actual device operation.

### DC Electrical Characteristics (Note 2)

Parameter and Inhibit Current cent Device Current	$V_{DD} = 15V,$ $V_{IN} = 0V$	V <sub>EE</sub> = 0V	Min	Max	Min	Тур	Max	Min	Max	Units
Current	$V_{IN} = 0V$	V <sub>EE</sub> = 0V								
	$V_{IN} = 0V$	$V_{EE} = 0V$								
cent Device Current	$V_{DD} = 15V$			-0.1		-10 <sup>-5</sup>	-0.1		-1.0	μА
cent Device Current	V <sub>IN</sub> = 15V	V <sub>EE</sub> = 0V		0.1		10 <sup>-5</sup>	0.1		1.0	
com Bornes Gamen	$V_{DD} = 5V$			5			5		150	
	$V_{DD} = 10V$			10			10		300	μΑ
	$V_{DD} = 15V$			20			20		600	
<sub>IS</sub> ) and Outputs (V <sub>OS</sub> )	)									
Resistance (Peak	$R_L = 10 \text{ k}\Omega$	$V_{DD} = 2.5V$ ,								
$E \le V_{IS} \le V_{DD}$	(any channel	$V_{EE} = -2.5V$		800		270	1050		1300	Ω
	selected)	or $V_{DD} = 5V$ ,		800		270	1030		1300	22
		$V_{EE} = 0V$								
		$V_{DD} = 5V$ ,								<b>†</b>
		$V_{EE} = -5V$		0.40		400	400			
		or V <sub>DD</sub> = 10V,		310		120	400		550	Ω
		$V_{EE} = 0V$								
		$V_{DD} = 7.5V$ ,								T
		$V_{EE} = -7.5V$								
		or V <sub>DD</sub> = 15V,		200		80	240		320	Ω
		$V_{EE} = 0V$								
" Resistance	$R_I = 10 \text{ k}\Omega$	$V_{DD} = 2.5V$ ,								1
en Any Two	(any channel	$V_{EF} = -2.5V$								
nels	selected)	or $V_{DD} = 5V$ ,				10				Ω
	,	$V_{EE} = 0V$								
		$V_{DD} = 5V$								$\vdash$
		$V_{EE} = -5V$								
		or V <sub>DD</sub> = 10V,				10				Ω
		V <sub>EF</sub> = 0V								
		$V_{DD} = 7.5V$ ,								<del>                                     </del>
		$V_{EE} = -7.5V$								
						5				Ω
Channel Leakage	V <sub>DD</sub> =7.5V.									+
•				+50		+0.01	+50		+500	nA
Channel Leakage										+
nt, all channels						_5.55				
(Common		D4052		+200		+0.04	+200		+2000	nA
`		D-1002		1200		±0.04	±200			'''
14)		CDANES		+200		+0.02	+200		+2000	
nt, a Ch nt, a	any channel "OFF" annel Leakage all channels	any channel "OFF" $O/l=\pm 7.5V$ , $I/O$ annel Leakage Inhibit = $7.5V$ $V_{DD} = 7.5V$ ,	any channel "OFF" $O/l=\pm 7.5V$ , $I/O=0V$ annel Leakage $I/O=0$	vannel Leakage vany channel "OFF" $O/D=7.5V$ , $O/D=7.5V$ , $O/D=7.5V$ vannel Leakage vany channel Leakage vany channel $O/D=7.5V$ , $O/D=0V$ vannel Leakage vany channels $O/D=7.5V$ , $O/D=$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

### DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	–55°C		+25°			125°C		Units
	Farameter		Min	Max	Min	Тур	Max	Min	Max	Ullits
Control In	Control Inputs A, B, C and Inhibit									
V <sub>IL</sub>	LOW Level Input Voltage	$V_{EE} = V_{SS} R_L = 1 k\Omega$ to $V_{SS}$								
		I <sub>IS</sub> <2 μA on all OFF Channels								
		$V_{IS} = V_{DD}$ thru 1 k $\Omega$								
		$V_{DD} = 5V$		1.5			1.5		1.5	
		$V_{DD} = 10V$		3.0			3.0		3.0	V
		V <sub>DD</sub> = 15V		4.0			4.0		4.0	
V <sub>IH</sub>	HIGH Level Input Voltage	V <sub>DD</sub> = 5	3.5		3.5			3.5		
		V <sub>DD</sub> = 10	7		7			7		V
		V <sub>DD</sub> = 15	11		11			11		

Note 2: All voltages measured with respect to V<sub>SS</sub> unless otherwise specified.

AC Electrical C	haracteristics	(Note 3)
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Symbol	$^{\circ}$ C, $t_r = t_f = 20$ ns, unless otherwise	Conditions	V	Min	Тур	Max	Units
Symbol			V <sub>DD</sub>	WIII			Units
t <sub>PZH,</sub>	Propagation Delay Time from	$V_{EE} = V_{SS} = 0V$	5V		600	1200	
$t_{PZL}$	Inhibit to Signal Output	$R_L = 1 \text{ k}\Omega$	10V		225	450	ns
	(channel turning on)	$C_L = 50 pF$	15V		160	320	
t <sub>PHZ,</sub>	Propagation Delay Time from	$V_{EE} = V_{SS} = 0V$	5V		210	420	
$t_{PLZ}$	Inhibit to Signal Output	$R_L = 1 \text{ k}\Omega$	10V		100	200	ns
	(channel turning off)	$C_L = 50 pF$	15V		75	150	
C <sub>IN</sub>	Input Capacitance						
	Control input				5	7.5	pF
	Signal Input (IN/OUT)				10	15	
C <sub>OUT</sub>	Output Capacitance						
	(common OUT/IN)						
	CD4051		10V		30		
	CD4052	$V_{EE} = V_{SS} = 0V$	10V		15		pF
	CD4053	EE 33 -	10V		8		
C <sub>IOS</sub>	Feedthrough Capacitance				0.2		pF
C <sub>PD</sub>	Power Dissipation Capacitance				0.2		Pi
ОРБ	CD4051				110		
	CD4052				140		pF
	CD4053				70		Pi
Cianal In	puts (V <sub>IS</sub> ) and Outputs (V <sub>OS</sub> )				70		
Signal III		D 4010				1	1
	Sine Wave Response	$R_L = 10 \text{ k}\Omega$	40) (				0,1
	(Distortion)	$f_{IS} = 1 \text{ kHz}$	10V		0.04		%
		$V_{IS} = 5 V_{p-p}$					
		$V_{EE} = V_{SI} = 0V$					
		$R_L=1~k\Omega,~V_{EE}=0V,~V_{IS}=5V_{p\text{-}p},$	10V		40		MHz
	"ON" (Sine Wave Input)	$20 \log_{10} V_{OS}/V_{IS} = -3 dB$					
	Feedthrough, Channel "OFF"	$R_L = 1 \text{ k}\Omega, V_{EE} = V_{SS} = 0V, V_{IS} = 5V_{p-p},$	10V		10		MHz
		$20 \log_{10} V_{OS}/V_{IS} = -40 \text{ dB}$					
	Crosstalk Between Any Two	$R_L = 1 \text{ k}\Omega, V_{EE} = V_{SS} = 0V, V_{IS}(A) = 5V_{p-p}$	10V		3		MHz
	Channels (frequency at 40 dB)	$20 \log_{10} V_{OS}(B)/V_{IS}(A) = -40 dB \text{ (Note 4)}$					
t <sub>PHL</sub>	Propagation Delay Signal	V <sub>EE</sub> = V <sub>SS</sub> = 0V	5V		25	55	
t <sub>PLH</sub>	Input to Signal Output	C <sub>L</sub> = 50 pF	10V		15	35	ns
			15V		10	25	
Control I	nputs, A, B, C and Inhibit					l	l
	Control Input to Signal	$V_{EE} = V_{SS} = 0V$ , $R_L = 10 \text{ k}\Omega$ at both ends					
	Crosstalk	of channel.	10V		65		mV (peak)
		Input Square Wave Amplitude = 10V					(1 - 1 - 1 - 1
t <sub>PHL</sub>	Propagation Delay Time from	V <sub>FF</sub> = V <sub>SS</sub> = 0V	5V		500	1000	
t <sub>PLH</sub>	Address to Signal Output	$C_L = 50 \text{ pF}$	10V		180	360	ns
PLH	(channels "ON" or "OFF")	OL - 00 bi	15V		120	240	113
	[(GHAHITEIS ON OF OFF.)		131		120	_ <del></del>	•

(channels "ON" or "OFF")

Note 3: AC Parameters are guaranteed by DC correlated testing.

Note 4: A, B are two arbitrary channels with A turned "ON" and B "OFF".

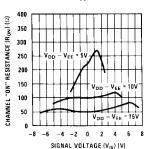
### **Special Considerations**

In certain applications the external load-resistor current may include both  $V_{DD}$  and signal-line components. To avoid drawing  $V_{DD}$  current when switch current flows into IN/OUT pin, the voltage drop across the bidirectional

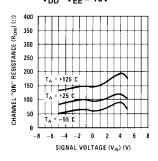
switch must not exceed 0.6V at  $T_A \le 25^{\circ}C$ , or 0.4V at  $T_A > 25^{\circ}C$  (calculated from  $R_{ON}$  values shown). No  $V_{DD}$  current will flow through  $R_L$  if the switch current flows into OUT/IN pin.

### **Typical Performance Characteristics**

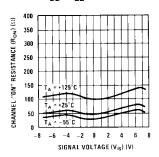
"ON" Resistance vs Signal Voltage for  $T_A=25^{\circ}\text{C}$ 



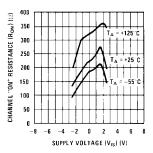
"ON" Resistance as a Function of Temperature for  $V_{DD}$ -  $V_{EE}$  = 10V

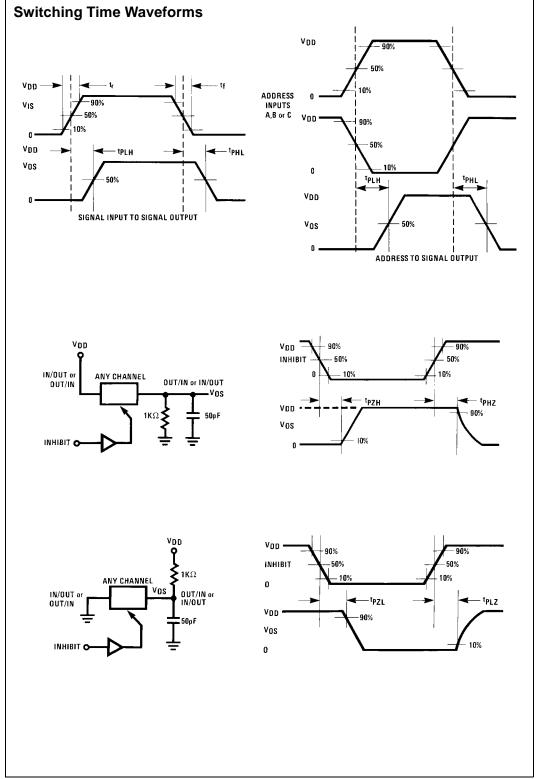


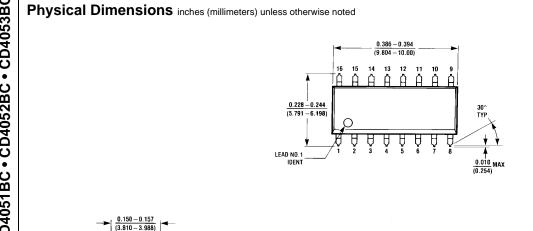
"ON" Resistance as a Function of Temperature for  $V_{DD}-V_{EE}=15V$ 

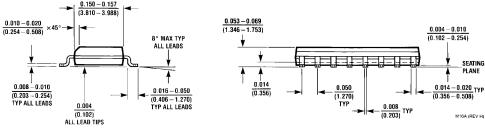


"ON" Resistance as a Function of Temperature for  $V_{DD} - V_{EE} = 5V$ 

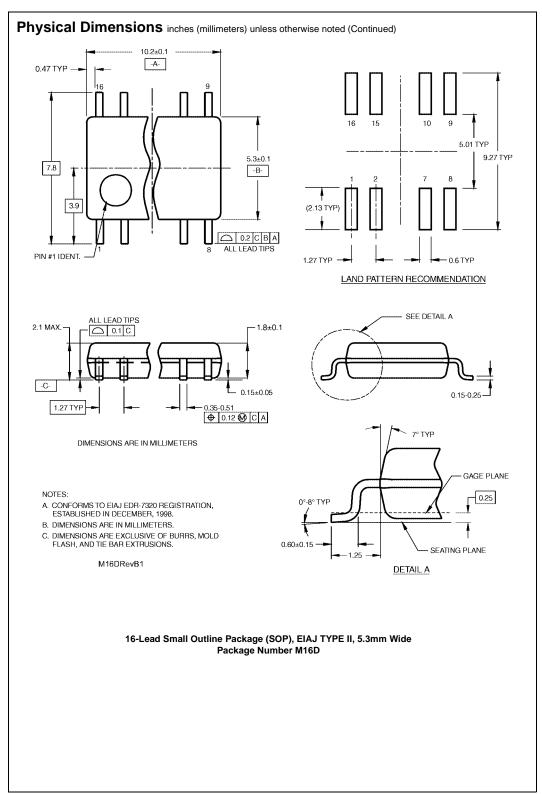


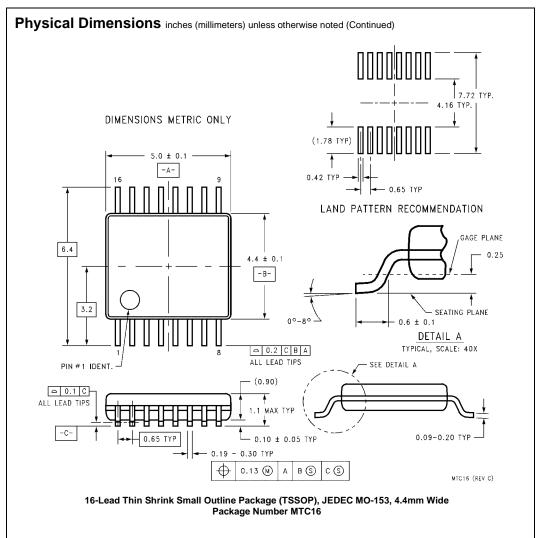






16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M16A





#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 0.740 - 0.7800.090 (18.80 - 19.81)(2.286)15 14 13 12 11 10 INDEX AREA 0.250 ± 0.010 $(6.350 \pm 0.254)$ PIN NO. 1 PIN NO. 1 1 2 3 4 5 6 7 8 2 IDENT IDENT OPTION 01 OPTION 02 0.065 0.130 ± 0.005 0.060 4° TYP 0.300 - 0.320(1.651) $(3.302 \pm 0.127)$ (1.524)OPTIONAL $\overline{(7.620 - 8.128)}$ 0.145 - 0.200 (3.683 - 5.080)950±50 $\frac{0.008 - 0.016}{(0.203 - 0.406)}$ TYP 0.020 0.280 (0.508)0.125 - 0.150(7.112) $0.030 \pm 0.015$ (3.175 - 3.810)MIN $(0.762 \pm 0.381)$ 0.014 - 0.023 $0.100 \pm 0.010$ (0.325 <del>+</del>0.040 <del>-</del>0.015 (0.356 - 0.584) $(2.540 \pm 0.254)$ $0.050 \pm 0.010$ N16E (REV F) TYP (8.255 **+**1.016 **-**0.381 $(1.270 \pm 0.254)$

16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N16E

TYP

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